

isc Silicon NPN Power Transistors

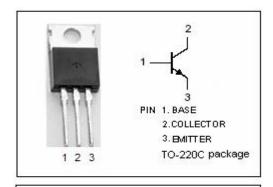
D44VH10

DESCRIPTION

- Low Collector-Emitter Saturation Voltage
- : V_{CE(sat})= 0.4V(Max)@ I_C = 8A
- Fast Switching Speeds
- Complement to Type D45VH10
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

 Designed for general purpose power amplification and switching such as output or driver stages in applications such as switching regulators, converters and power amplifier.



ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CEO}	Collector-Emitter Voltage	80	٧
V _{CBO}	Collector-Base Voltage	100	V
V_{EBO}	Emitter-Base Voltage	7.0	V
Ic	Collector Current-Continuous	15	Α
Pc	Collector Power Dissipation @T _C =25 ℃	83	W
Tj	Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.5	°C/W

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<u> </u>	-	15,00°.D	_	₽ J R ⋖
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,	DUL	m	Silving and the second]
,	DIM	MIN	Silving and the second	
	Α	MIN 15.50	MAX 15.90	
	A B	MIN 15.50 9.80	MAX 15.90 10.20	
	A B	MIN 15.50 9.80	MAX 15.90 10.20 4.50	
	B C D	MIN 15.50 9.80 4.20 0.70	MAX 15.90 10.20 4.50 0.90	
	B C D	MIN 15.50 9.80 4.20 0.70 3.40	MAX 15.90 10.20 4.50 0.90	82
	B C D F	MIN 15.50 9.80 4.20 0.70 3.40 4.98	MAX 15.90 10.20 4.50 0.90 3.70 5.18	22
	B C D F G	MIN 15.50 9.80 4.20 0.70 3.40 4.98 2.68	MAX 15.90 10.20 4.50 0.90 3.70 5.18 2.90	2.
	A B C D F G H	MIN 15.50 9.80 4.20 0.70 3.40 4.98 2.68 0.44	MAX 15.90 10.20 4.50 0.90 3.70 5.18 2.90 0.60	8.
	B C D F G H	MIN 15.50 9.80 4.20 0.70 3.40 4.98 2.68 0.44 12.80	MAX 15.90 10.20 4.50 0.90 3.70 5.18 2.90 0.60 13.40	82
	B C D F G H J K	MIN 15.50 9.80 4.20 0.70 3.40 4.98 2.68 0.44 12.80 1.20	MAX 15.90 10.20 4.50 0.90 3.70 5.18 2.90 0.60 13.40 1.45 2.90	82
	B C D F G H J K	MIN 15.50 9.80 4.20 0.70 3.40 4.98 2.68 0.44 12.80	MAX 15.90 10.20 4.50 0.90 3.70 5.18 2.90 0.60 13.40 1.45 2.90	82
	B C D F G H J K	MIN 15.50 9.80 4.20 0.70 3.40 4.98 2.68 0.44 12.80 1.20 2.70 2.30	MAX 15.90 10.20 4.50 0.90 3.70 5.18 2.90 0.60 13.40 1.45 2.90	82
	B C D F G H J K	MIN 15.50 9.80 4.20 0.70 3.40 4.98 2.68 0.44 12.80 1.20	MAX 15.90 10.20 4.50 0.90 3.70 5.18 2.90 0.60 13.40	82

isc website: www.iscsemi.com



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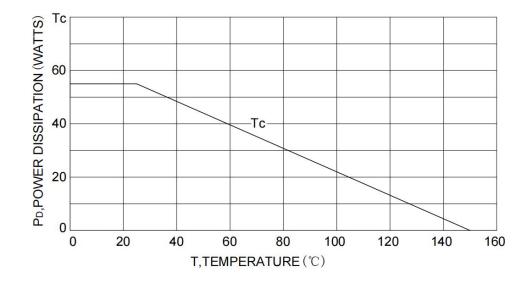
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ELECTRICAL CHARACTERISTICS

 T_{C} =25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	7	-	V
V _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA; I _B = 0	80	-	V
V _{CBO}	Collector-Base Breakdown Voltage	I _C =1mA; I _B = 0	100	-	V
I _{EBO}	Emitter Cutoff Current	V _{EB} = 7V; I _C = 0	-	10	μА
I _{CEO}	Collector-Emitter Cutoff Current	V _{CE} = 80V; I _B = 0	-	1	mA
I _{CBO}	Collector-Emitter Cutoff Current	V _{CE} = 80V; I _E = 0	-	100	μА
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 8A ;I _B = 0.4 A	-	0.4	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 8A ;I _B = 0.4 A	-	1.2	V
h _{FE-1}	DC Current Gain	I _C = 2A ; V _{CE} = 1V	35	-	-
h _{FE-2}	DC Current Gain	I _C = 4A ; V _{CE} = 1V	20	-	-

Power and temperature curve



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